

74AC541, 74ACT541

Octal Buffer/Line Driver with 3-STATE Outputs

Features

- I_{CC} and I_{OZ} reduced by 50%
- 3-STATE outputs
- Inputs and outputs opposite side of package, allowing easier interface to microprocessors
- Output source/sink 24mA
- 74AC541 is a non-inverting option of the 74AC540
- 74ACT541 has TTL-compatible inputs

General Description

The 74AC541 and 74ACT541 are octal buffer/line drivers designed to be employed as memory and address drivers, clock drivers and bus oriented transmitter/receivers.

These devices are similar in function to the 74AC244 and 74ACTC244 while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes these devices especially useful as an output port for microprocessors, allowing ease of layout and greater PC board density.

Ordering Information

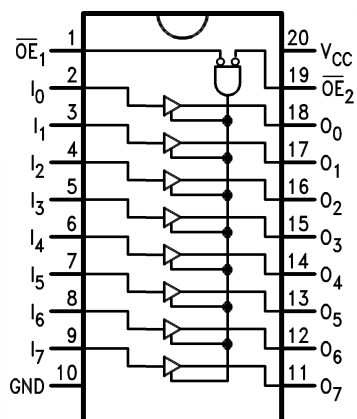
Order Number	Package Number	Package Description
74AC541SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74AC541SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74AC541MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74AC541PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
74ACT541SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74ACT541MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

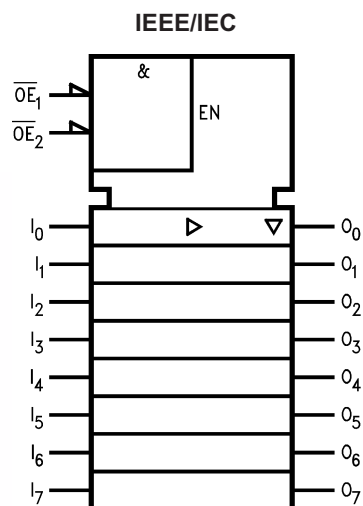


All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagram



Logic Symbol



Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level

X = Immaterial

L = LOW Voltage Level

Z = High Impedance

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V_{CC}	Supply Voltage	−0.5V to +7.0V
I_{IK}	DC Input Diode Current $V_I = -0.5V$	−20mA
	$V_I = V_{CC} + 0.5$	+20mA
V_I	DC Input Voltage	−0.5V to $V_{CC} + 0.5V$
I_{OK}	DC Output Diode Current $V_O = -0.5V$	−20mA
	$V_O = V_{CC} + 0.5V$	+20mA
V_O	DC Output Voltage	−0.5V to $V_{CC} + 0.5V$
I_O	DC Output Source or Sink Current	±50mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current per Output Pin	±50mA
T_{STG}	Storage Temperature	−65°C to +150°C
T_J	Junction Temperature	140°C

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
V_{CC}	Supply Voltage AC	2.0V to 6.0V
	ACT	4.5V to 5.5V
V_I	Input Voltage	0V to V_{CC}
V_O	Output Voltage	0V to V_{CC}
T_A	Operating Temperature	−40°C to +85°C
$\Delta V / \Delta t$	Minimum Input Edge Rate, AC Devices: V_{IN} from 30% to 70% of V_{CC} , V_{CC} @ 3.3V, 4.5V, 5.5V	125mV/ns
$\Delta V / \Delta t$	Minimum Input Edge Rate, ACT Devices: V_{IN} from 0.8V to 2.0V, V_{CC} @ 4.5V, 5.5V	125mV/ns

DC Electrical Characteristics for AC

Symbol	Parameter	V _{CC} (V)	Conditions	T _A = +25°C		T _A = −40°C to +85°C		Units
				Typ.	Guaranteed Limits			
V _{IH}	Minimum HIGH Level Input Voltage	3.0	V _{OUT} = 0.1V or V _{CC} − 0.1V	1.5	2.1	2.1		V
		4.5		2.25	3.15	3.15		
		5.5		2.75	3.85	3.85		
V _{IL}	Maximum LOW Level Input Voltage	3.0	V _{OUT} = 0.1V or V _{CC} − 0.1V	1.5	0.9	0.9		V
		4.5		2.25	1.35	1.35		
		5.5		2.75	1.65	1.65		
V _{OH}	Minimum HIGH Level Output Voltage	3.0	I _{OUT} = −50μA	2.99	2.9	2.9		V
		4.5		4.49	4.4	4.4		
		5.5		5.49	5.4	5.4		
		3.0	V _{IN} = V _{IL} or V _{IH} , I _{OH} = −12mA		2.56	2.46		
		4.5	V _{IN} = V _{IL} or V _{IH} , I _{OH} = −24mA		3.86	3.76		
		5.5	V _{IN} = V _{IL} or V _{IH} , I _{OH} = −24mA ⁽¹⁾		4.86	4.76		
V _{OL}	Maximum LOW Level Output Voltage	3.0	I _{OUT} = 50μA	0.002	0.1	0.1		V
		4.5		0.001	0.1	0.1		
		5.5		0.001	0.1	0.1		
		3.0	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 12mA		0.36	0.44		
		4.5	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 24mA		0.36	0.44		
		5.5	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 24mA ⁽¹⁾		0.36	0.44		
I _{IN} ⁽²⁾	Maximum Input Leakage Current	5.5	V _I = V _{CC} , GND		±0.1	±1.0		μA
I _{OZ}	Maximum 3-STATE Leakage Current	5.5	V _I (OE) = V _{IL} , V _{IH} ; V _I = V _{CC} , GND; V _O = V _{CC} , GND		±0.25	±2.5		μA
I _{OLD}	Minimum Dynamic Output Current ⁽³⁾	5.5	V _{OLD} = 1.65V Max.			75		mA
I _{OHD}		5.5	V _{OHD} = 3.85V Min.			−75		mA
I _{CC} ⁽²⁾	Maximum Quiescent Supply Current	5.5	V _{IN} = V _{CC} or GND		4.0	40.0		μA

Notes:

1. All outputs loaded; thresholds on input associated with output under test.
2. I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.
3. Maximum test duration 2.0ms, one output loaded at a time.

DC Electrical Characteristics for ACT

Symbol	Parameter	V _{CC} (V)	Conditions	T _A = +25°C		T _A = −40°C to +85°C		Units
				Typ.	Guaranteed Limits			
V _{IH}	Minimum HIGH Level Input Voltage	4.5	V _{OUT} = 0.1V or V _{CC} − 0.1V	1.5	2.0	2.0		V
		5.5		1.5	2.0	2.0		
V _{IL}	Maximum LOW Level Input Voltage	4.5	V _{OUT} = 0.1V or V _{CC} − 0.1V	1.5	0.8	0.8		V
		5.5		1.5	0.8	0.8		
V _{OH}	Minimum HIGH Level Output Voltage	4.5	I _{OUT} = −50μA	4.49	4.4	4.4		V
		5.5		5.49	5.4	5.4		
		4.5	V _{IN} = V _{IL} or V _{IH} , I _{OH} = −24mA		3.86	3.76		
		5.5	V _{IN} = V _{IL} or V _{IH} , I _{OH} = −24mA ⁽⁴⁾		4.86	4.76		
V _{OL}	Maximum LOW Level Output Voltage	4.5	I _{OUT} = 50μA	0.001	0.1	0.1		V
		5.5		0.001	0.1	0.1		
		4.5	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 24mA		0.36	0.44		
		5.5	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 24mA ⁽⁴⁾		0.36	0.44		
I _{IN}	Maximum Input Leakage Current	5.5	V _I = V _{CC} , GND		±0.1	±1.0		μA
I _{OZ}	Maximum 3-STATE Leakage Current	5.5	V _I = V _{IL} , V _{IH} ; V _O = V _{CC} , GND		±0.25	±2.5		μA
I _{CCT}	Maximum I _{CC} /Input	5.5	V _I = V _{CC} − 2.1V	0.6		1.5		mA
I _{OLD}	Minimum Dynamic Output Current ⁽⁵⁾	5.5	V _{OLD} = 1.65V Max.			75		mA
I _{OHD}		5.5	V _{OHD} = 3.85V Min.			−75		mA
I _{CC}	Maximum Quiescent Supply Current	5.5	V _{IN} = V _{CC} or GND		4.0	40.0		μA

Notes:

4. All outputs loaded; thresholds on input associated with output under test.
 5. Maximum test duration 2.0ms, one output loaded at a time.

AC Electrical Characteristics for AC

Symbol	Parameter	V_{CC} (V) ⁽⁶⁾	$T_A = +25^\circ\text{C}$, $C_L = 50\text{pF}$			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$, $C_L = 50\text{pF}$		Units
			Min.	Typ.	Max.	Min.	Max.	
t_{PLH}	Propagation Delay, Data to Output	3.3	2.0	5.5	8.0	1.5	9.0	ns
		5.0	1.5	4.0	6.0	1.0	6.5	
t_{PHL}	Propagation Delay, Data to Output	3.3	2.0	5.5	8.0	1.5	8.5	ns
		5.0	1.5	4.0	6.0	1.0	6.5	
t_{PZH}	Output Enable Time	3.3	3.0	8.0	11.5	3.0	12.5	ns
		5.0	2.0	6.0	8.5	1.5	9.5	
t_{PZL}	Output Enable Time	3.3	2.5	7.0	10.0	2.5	11.5	ns
		5.0	1.5	5.5	7.5	1.0	8.5	
t_{PHZ}	Output Disable Time	3.3	3.5	9.0	12.5	2.5	14.0	ns
		5.0	2.0	7.0	9.5	1.0	10.5	
t_{PLZ}	Output Disable Time	3.3	2.5	6.5	9.5	2.0	10.5	ns
		5.0	2.0	5.5	7.5	1.0	8.5	

Note:

6. Voltage range 3.3 is $3.3\text{V} \pm 0.3\text{V}$. Voltage range 5.0 is $5.0\text{V} \pm 0.5\text{V}$.

AC Electrical Characteristics for ACT

Symbol	Parameter	V_{CC} (V) ⁽⁷⁾	$T_A = +25^\circ\text{C}$, $C_L = 50\text{pF}$			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$, $C_L = 50\text{pF}$		Units
			Min.	Typ.	Max.	Min	Max	
t_{PLH}	Propagation Delay, Data to Output	5.0	2.0	4.5	7.0	2.0	7.5	ns
t_{PHL}			2.0	5.5	7.0	2.0	7.5	
t_{PZH}	Output Enable Time	5.0	2.0	5.0	9.0	2.0	9.5	ns
t_{PZL}			2.0	6.5	9.0	2.0	9.5	
t_{PHZ}	Output Disable Time	5.0	1.5	5.5	7.5	1.5	8.0	ns
t_{PLZ}			1.5	5.5	7.5	1.5	8.0	

Note:

7. Voltage range 5.0 is $5.0\text{V} \pm 0.5\text{V}$.

Capacitance

Symbol	Parameter	Conditions	Typ.	Units
C_{IN}	Input Capacitance	$V_{CC} = \text{OPEN}$	4.5	pF
C_{PD}	Power Dissipation Capacitance for AC	$V_{CC} = 5.0\text{V}$	30.0	pF
	Power Dissipation Capacitance for ACT		70.0	

Physical Dimensions

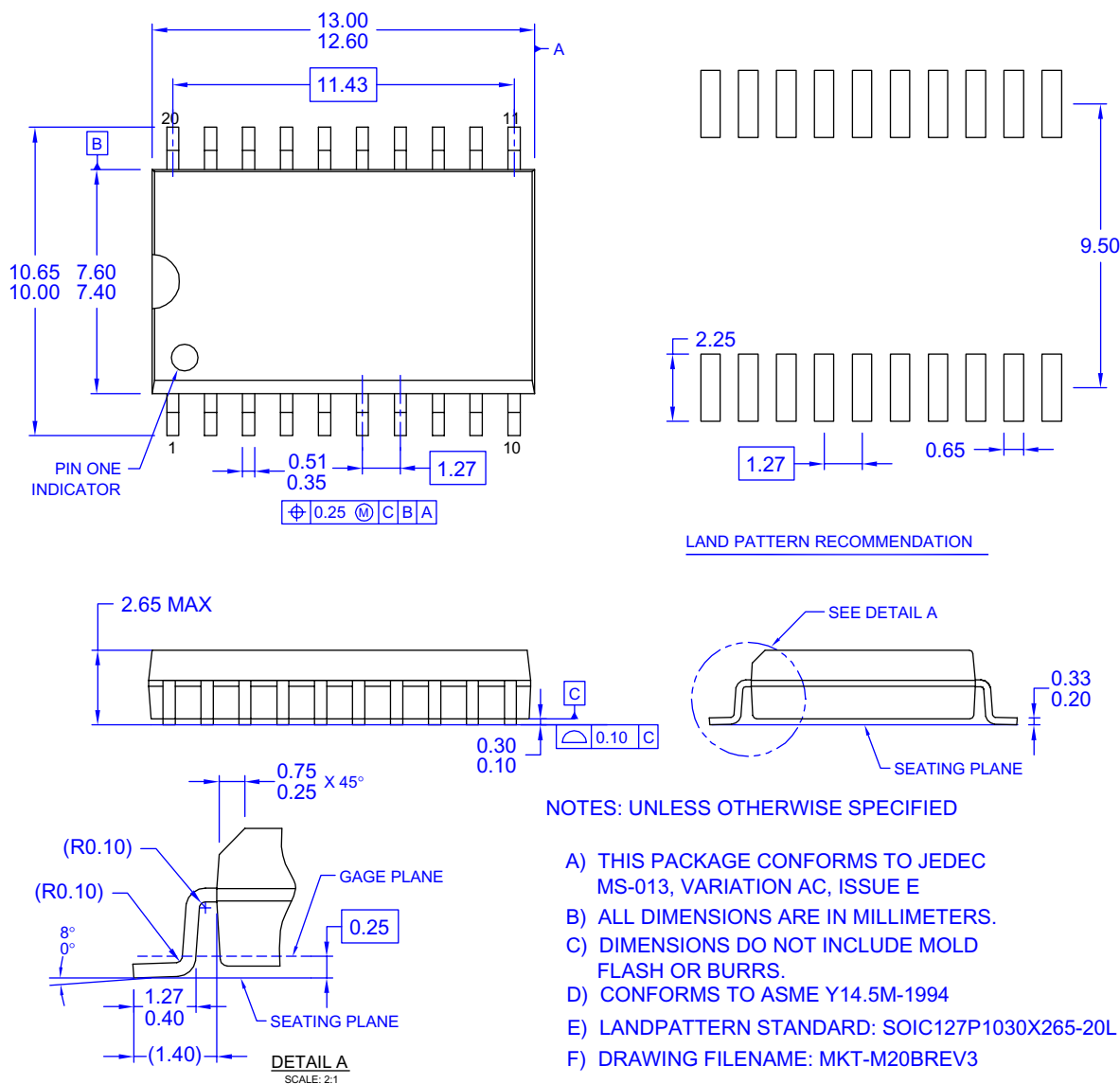


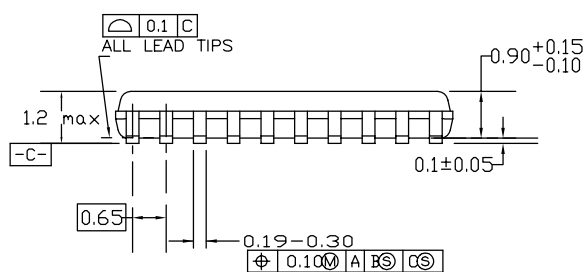
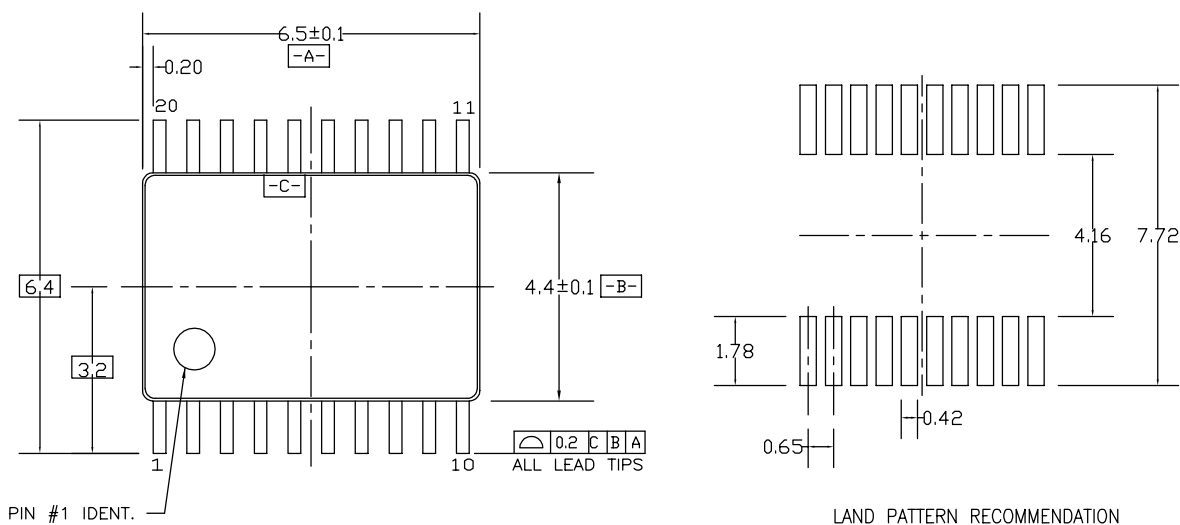
Figure 1. 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide

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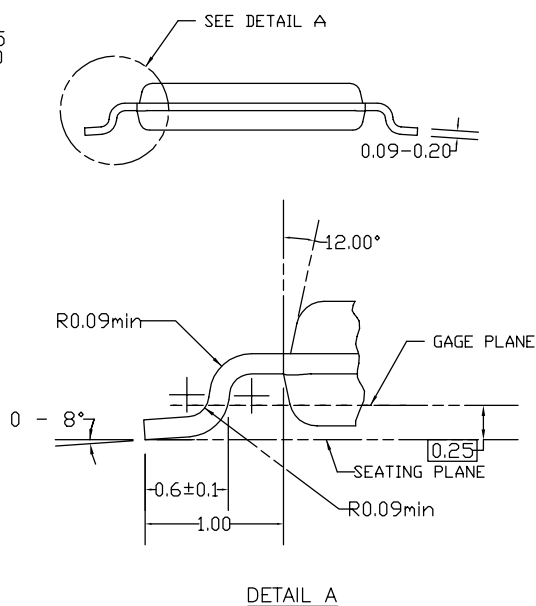
Physical Dimensions (Continued)



DIMENSIONS ARE IN MILLIMETERS

NOTES:

- CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.
- DIMENSIONS ARE IN MILLIMETERS.
- DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.
- DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.



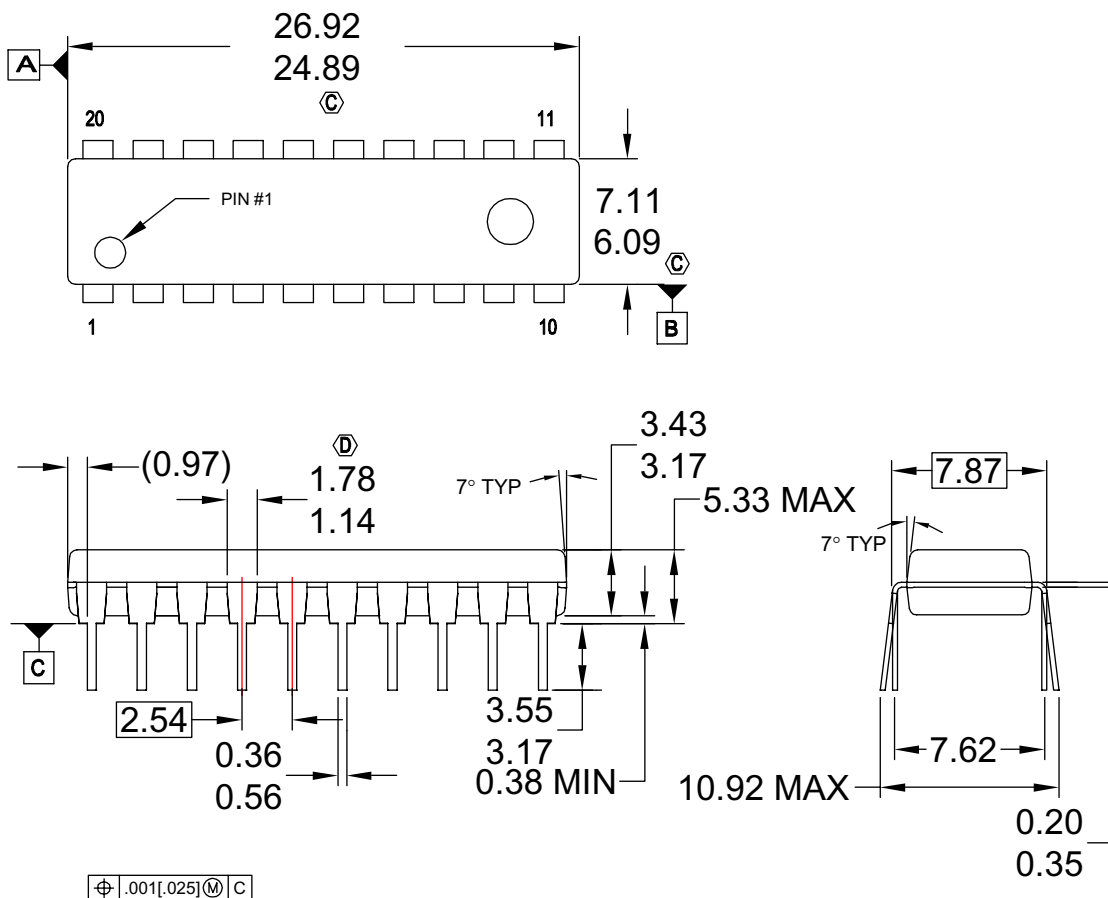
MTC20REV D1

Figure 3. 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

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Physical Dimensions (Continued)**NOTES:**

- A. CONFORMS TO JEDEC REGISTRATION MS-001, VARIATIONS AD.
- B. ALL DIMENSIONS ARE IN MILLIMETERS
- C. DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.25MM.
- D. DOES NOT INCLUDE DAMBAR PROTRUSIONS. DAMBAR PROTRUSIONS SHALL NOT EXCEED 0.25MM.
- E. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- F. DRAWING FILE NAME: N20AREV8

Figure 4. 20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

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